MBRS735 THRU MBRS760

SCHOTTKY BARRIER RECTIFIER REVERSE VOLTAGE: 35

FORWARD CURRENT:

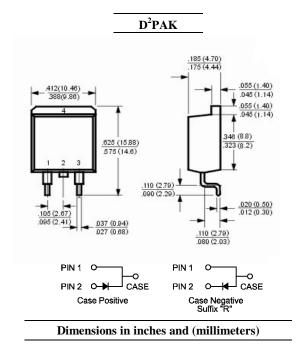
35 to 60 VOLTS 7.5 AMPERE

FEATURES

- \cdot For surface mounted application
- \cdot Metal silicon junction, majority carrier conduction
- \cdot Guard ring for overvoltage protection
- \cdot Low power loss, high efficiency
- For use in low voltage, high frequency inverters, free whelling, and polarity protection applications
- High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case

MECHANICAL DATA

Case: Molded plastic, D²PAK Epoxy: UL 94V-O rate flame retardant Terminals: Leads solderable per MIL-STD-202 method 208 guaranteed Polarity: As marked Mounting position: Any Weight: 0.06ounce, 1.70gram



Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase, half wave, $60H_Z$, resistive or inductive load. For capacitive load, derate current by 20%.

	Symbols	MBRS735	MBRS745	MBRS750	MBRS760	Units
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	35	45	50	60	Volts
Maximum RMS Voltage	V _{RMS}	24	31	35	42	Volts
Maximum DC Blocking Voltage	V _{DC}	20	30	40	50	Volts
Maximum Average Forward Rectified Current	I _(AV) 7.5					Amp
See Fig. 1	I _(AV)	7.5				
Peak repetitive forward current (sq. wave, 20 KHz)	I _{FRM} 15					Amp
at $T_C = 105^{\circ}C$	I _{FRM}	15				
Peak Forward Surge Current,						
8.3ms single half-sine-wave	I _{FSM} 150				Amp	
superimposed on rated load (JEDEC method)						
Peak repetitive reverse current at tp = 2.0µs, 1KHz	I _{RRM}	1.0		0.5		Amp
at $I_F = 7.5A$, $T_C = 25^{\circ}C$		-		0.75		Volts
Maximum Forward at $I_F = 7.5A$, $T_C = 125^{\circ}C$	V _F	0.57		0.65		
Voltage (Note 1) at $I_F = 15A$, $T_C = 25^{\circ}C$		0.84		-		
at $I_F = 15A$, $T_C = 125^{\circ}C$		0.72		-		
Maximum Reverse Current at T _C =25°C	I _R	0.1		0.5		mAmp
at Rated DC Blocking Voltage T _C =125°C		1	.5	4	50	mamp
Voltage rate of change (rated V _R)	dv/dt	10,000				V/µs
Typical Thermal Resistance	$R_{\theta JC}$	3.0				°C/W
Operating Temperature Range	TJ	-55 to +150				ĉ
Storage Temperature Range	Tstg	-55 to +175				Ĉ

NOTES:

1- Pulse test: 300µs pulse width, 1% duty cycle



RATINGS AND CHARACTERISTIC CURVES

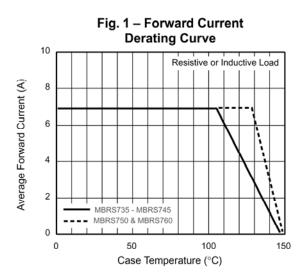
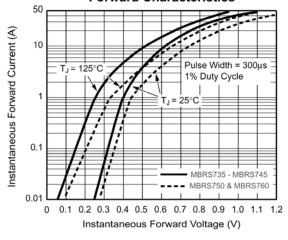
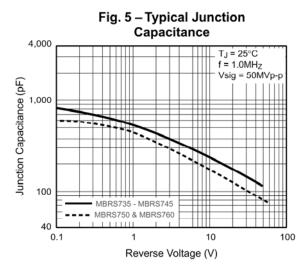


Fig. 3 – Typical Instantaneous Forward Characteristics





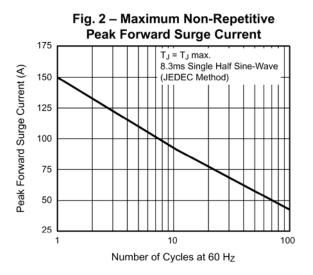


Fig. 4 – Typical Reverse Characteristics

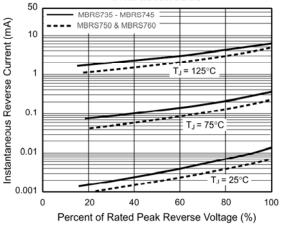


Fig. 6 – Typical Transient Thermal Impedance

